TOSHIBA IGBT Module Silicon N Channel IGBT

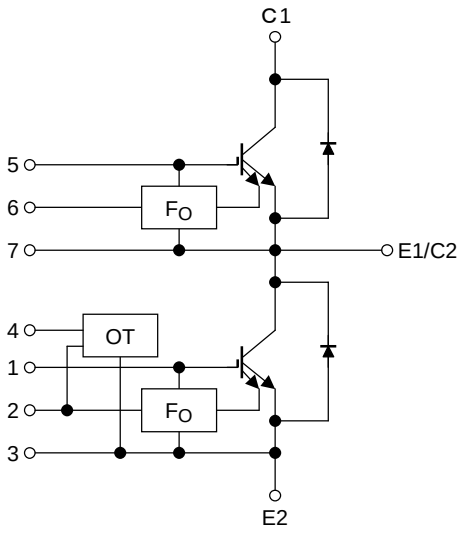
MG600J2YS60A(600V/600A 2in1)

High Power Switching Applications

Motor Control Applications

- Integrates a complete half bridge power circuit and fault-signal output circuit in one package. (short circuit and over temperature)
- The electrodes are isolated from case.
- Low thermal resistance
- $V_{CE\ (sat)}$ = 2.1 V (typ.)

Equivalent Circuit

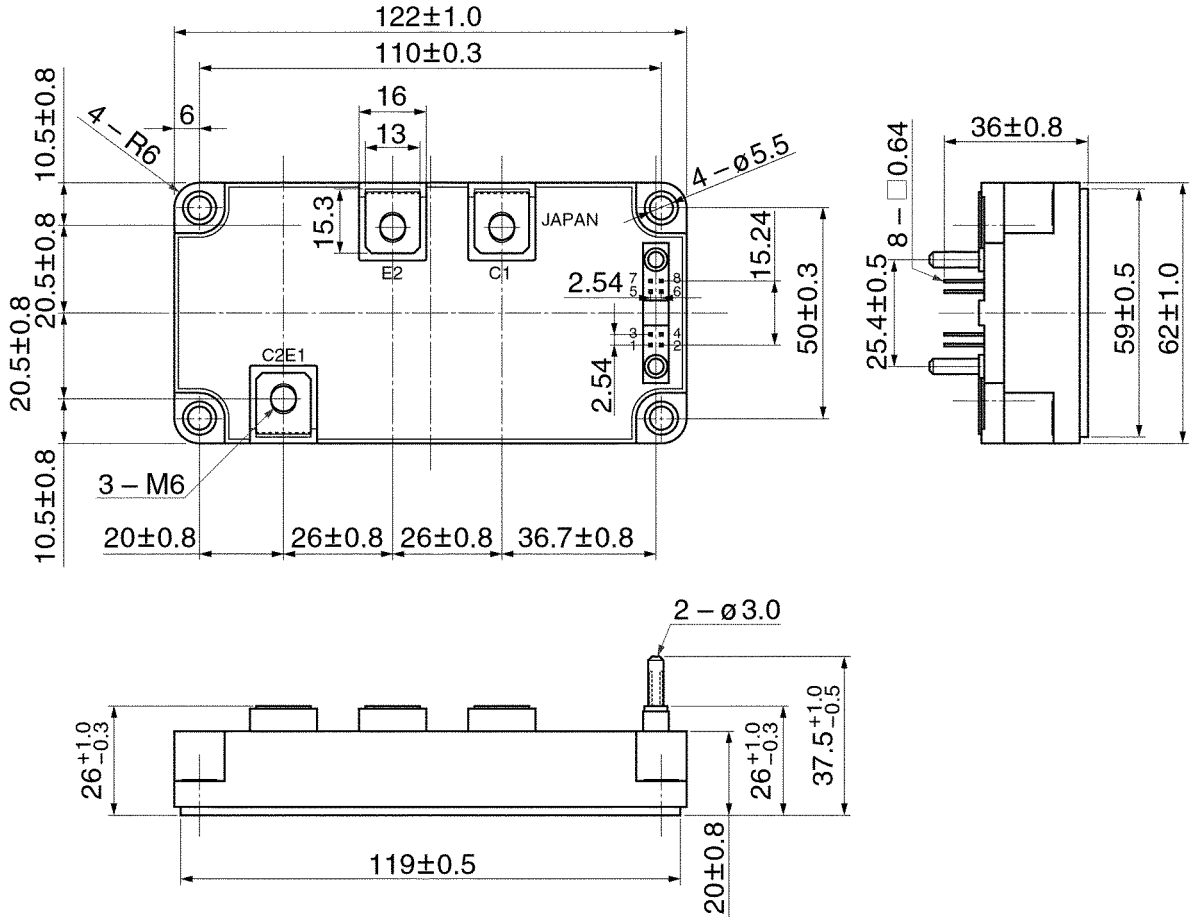


Signal terminal

1.	G (L)	2.	F_O (L)	3.	E (L)	4.	V_D
5.	G (H)	6.	F_O (H)	7.	E (H)	8.	Open

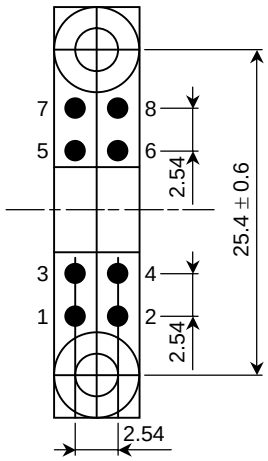
Package Dimensions: 2-123C1B

Unit: mm



1.	G (L)	2.	F_O (L)	3.	E (L)	4.	V_D
5.	G (H)	6.	F_O (H)	7.	E (H)	8.	Open

Signal Terminal Layout



1.	G (L)	2.	F_O (L)	3.	E (L)	4.	V_D
5.	G (H)	6.	F_O (H)	7.	E (H)	8.	Open

Weight: 375 g

Maximum Ratings (Ta = 25°C)

Stage	Characteristics		Symbol	Rating	Unit
Inverter	Collector-emitter voltage		V_{CES}	600	V
	Gate-emitter voltage		V_{GES}	±20	V
	Collector current	DC	I_C	600	A
		1 ms	I_{CP}	1200	
	Forward current	DC	I_F	600	A
		1 ms	I_{FM}	1200	
	Collector power dissipation (Tc = 25°C)		P_C	2770	W
Control	Control voltage (OT)		V_D	20	V
	Fault input voltage		VF_O	20	V
	Fault input current		IF_O	20	mA
Module	Junction temperature		T_j	150	°C
	Storage temperature range		T_{stg}	−40~125	°C
	Operation temperature range		T_{ope}	−20~100	°C
	Isolation voltage		V_{isol}	2500 (AC 1 min)	V
	Screw torque		—	3 (M5)	N·m

Electrical Characteristics (T_j = 25°C)

1. Inverter Stage

Characteristics		Symbol	Test Condition		Min	Typ.	Max	Unit
Gate leakage current		I_{GES}	V_{GE} = ±20 V, V_{CE} = 0		—	—	+3/−4	mA
			V_{GE} = +10 V, V_{CE} = 0		—	—	100	nA
Collector cut-off current		I_{CES}	V_{CE} = 600 V, V_{GE} = 0		—	—	1.0	mA
Gate-emitter cut-off voltage		$V_{GE\ (off)}$	V_{CE} = 5 V, I_C = 600 mA		5.0	6.5	8.0	V
Collector-emitter saturation voltage		$V_{CE\ (sat)}$	V_{GE} = 15 V, I_C = 600 A	Tj = 25°C	—	2.1	2.4	V
				Tj = 125°C	—	—	2.6	
Input capacitance		C_{ies}	V_{CE} = 10 V, V_{GE} = 0, f = 1 MHz		—	5000	—	pF
Switching time	Turn-on delay time	$t_{d\ (on)}$	V_{CC} = 300 V, I_C = 600 A V_{GE} = ±15 V, R_G = 5.1 Ω (Note 1)		0.10	—	1.00	μs
	Turn-off time	t_{off}			—	—	2.00	
	Fall time	t_f			—	—	0.50	
Reverse recovery time		t_{rr}			—	—	0.50	
Forward voltage		V_F	I_F = 600 A		—	2.1	2.4	V

Note 1: Switching time test circuit & timing chart

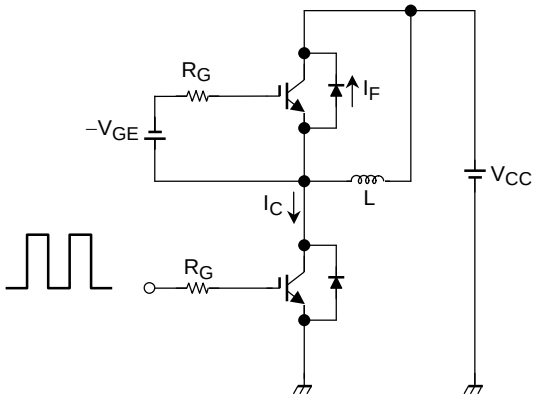
2. Control (Tc = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Fault output current	OC	V_{GE} = 15 V	720	—	—	A
Over temperature	OT	—	100	—	125	°C
Fault output delay time	$t_{d\ (Fo)}$	V_{CC} = 300 V, V_{GE} = ±15 V	—	—	6.5	μs

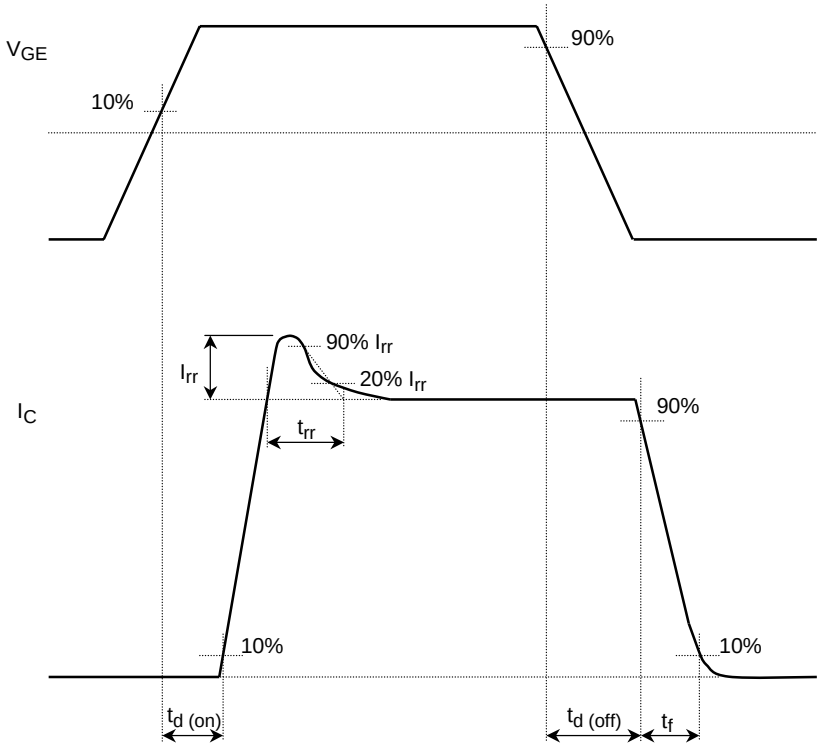
3. Module (Tc = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Junction to case thermal resistance	$R_{th\ (j\text{-}c)}$	Inverter IGBT stage	—	—	0.045	°C/W
		Inverter FRD stage	—	—	0.068	
Case to fin thermal resistance	$R_{th\ (c\text{-}f)}$	With silicon compound	—	0.013	—	°C/W

Switching Time Test Circuit



Timing Chart



Remark

<Short circuit capability condition>

- Short circuit capability is 6 μs after fault output signal.
  Please keep following condition to use fault output signal.
  - $V_{CC} \leqq 375$ V
  - $13.8 \text{ V} \leqq V_{GE} \leqq 16.0$ V
  - $R_G \geqq 5.1\ \Omega$
  - $T_j \leqq 50°C$

<Gate voltage>

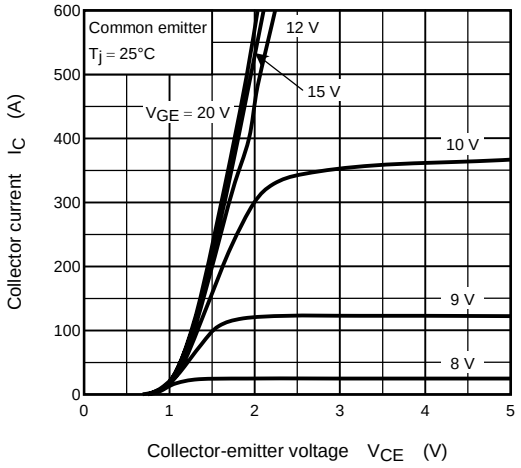
- To use this product, V_{GE} must be provided higher than 13.8 V.
  In case V_{GE} is less than 13.8 V, fault signal F_O may not be output even under error conditions.

<For parallel use>

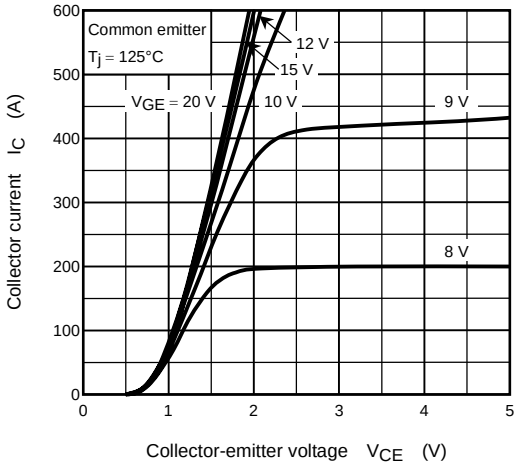
- For parallel use of this product, please use the same rank for both $V_{CE\ (sat)}$ and VF among IGBT in parallel without fail.

$V_{CE\ (sat)}$	V_F	Min	Max
18	B	1.5	1.8
20	C	1.7	2.0
22	D	1.9	2.2
24	E	2.1	2.4

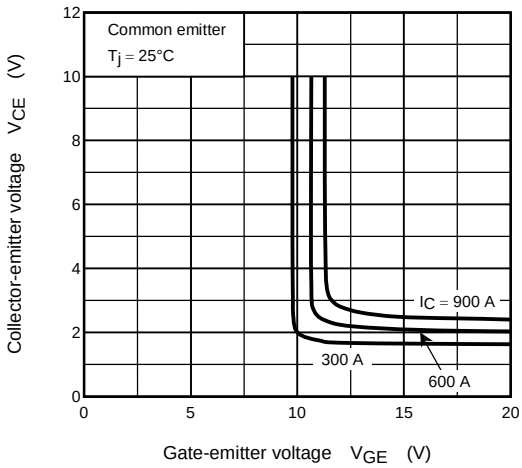
$I_C - V_{CE}$



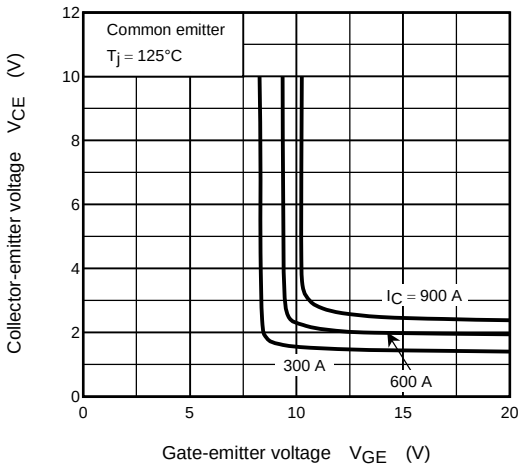
$I_C - V_{CE}$



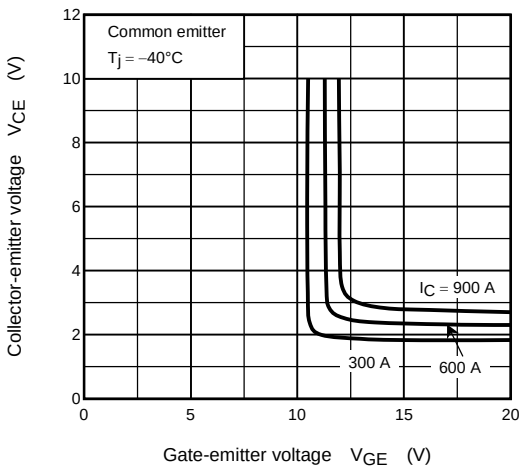
$V_{CE} - V_{GE}$



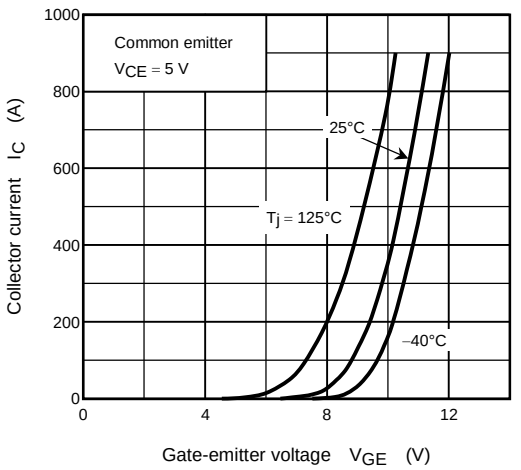
$V_{CE} - V_{GE}$



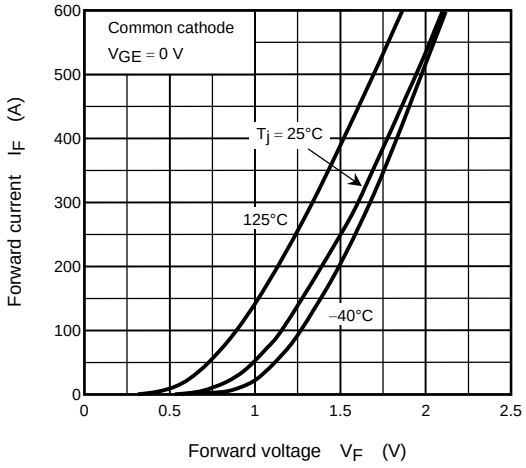
$V_{CE} - V_{GE}$



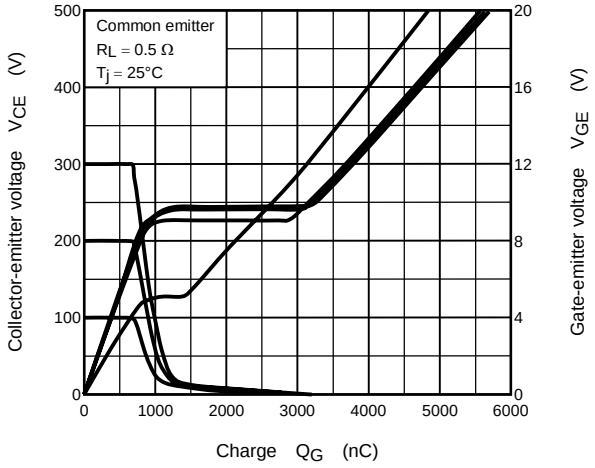
$I_C - V_{GE}$



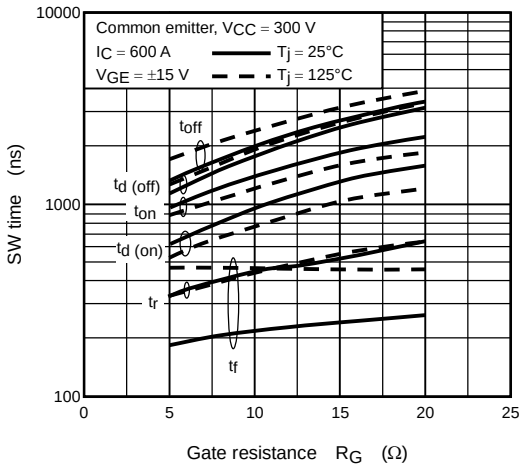
$I_F - V_F$



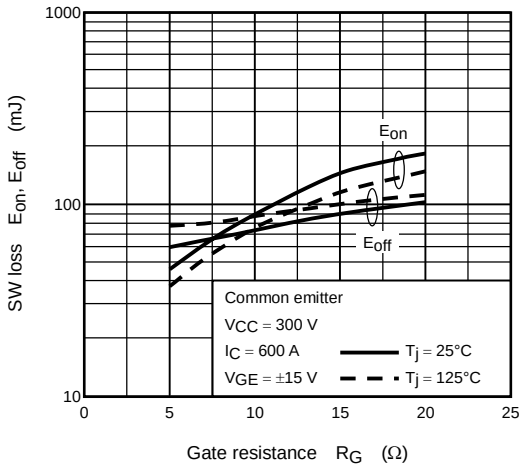
$V_{CE}, V_{GE} - Q_G$



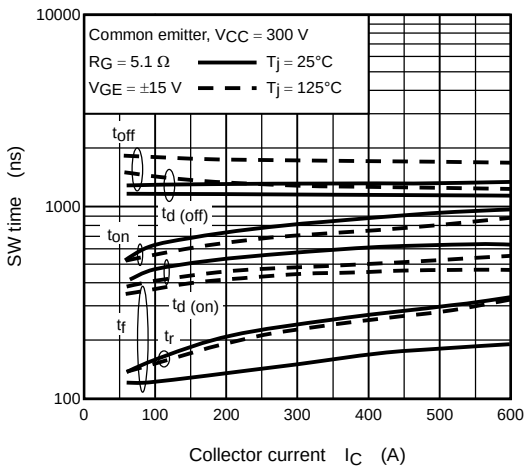
SW time – R_G



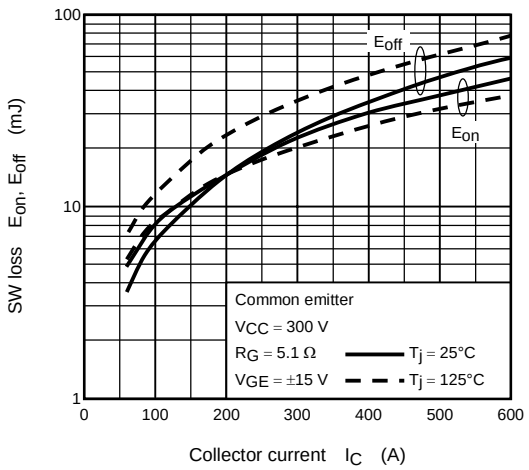
$E_{on}, E_{off} - R_G$



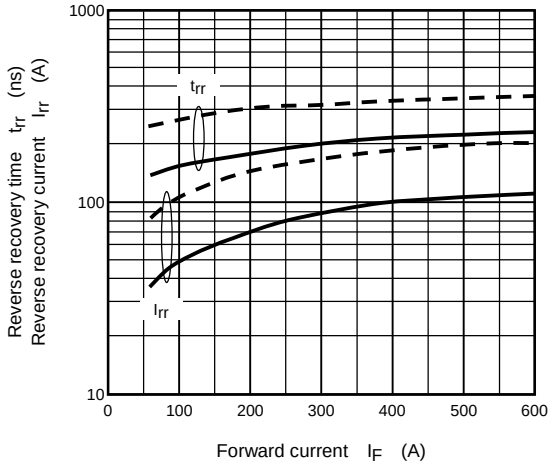
SW time – I_C



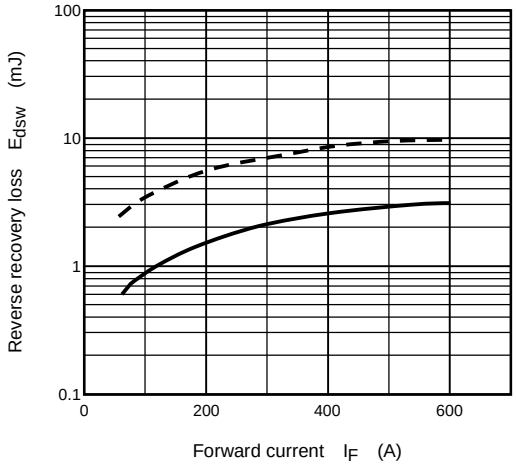
$E_{on}, E_{off} - I_C$



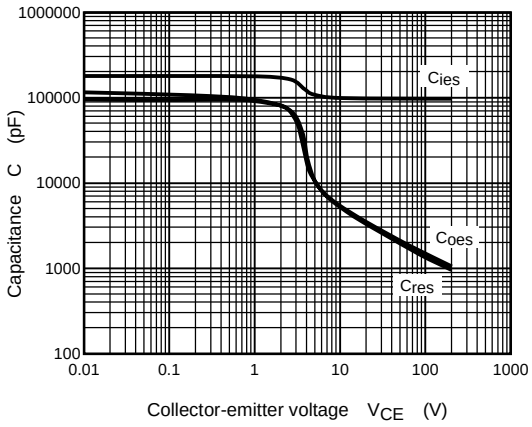
I_{rr}, t_{rr} – I_F



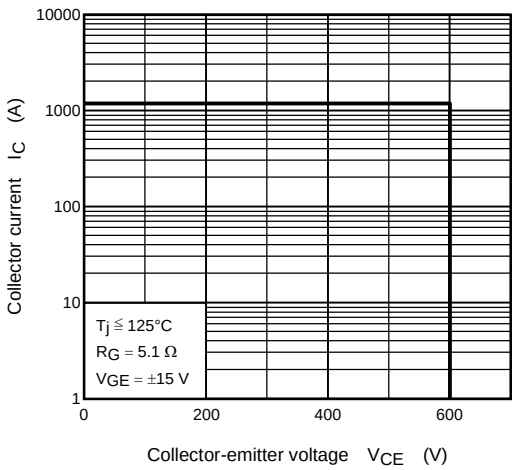
E_{dsw} – I_F



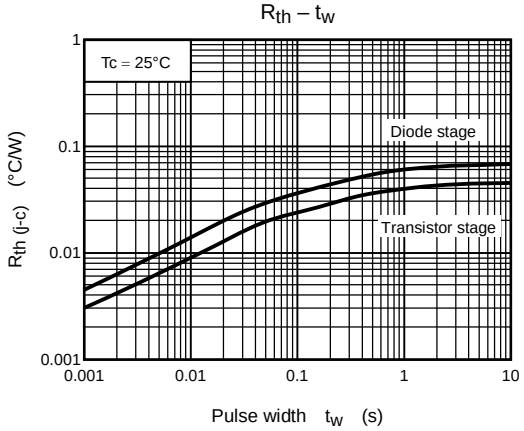
C – V_{CE}



Reverse bias SOA



R_{th} – t_w



RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the “Handling Guide for Semiconductor Devices,” or “TOSHIBA Semiconductor Reliability Handbook” etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury (“Unintended Usage”). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer’s own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.